## 80 mA CMOS Low Ig **Low-Dropout Voltage Regulator**

This series of fixed output low-dropout linear regulators are designed for handheld communication equipment and portable battery powered applications which require low quiescent. This series features an ultra-low quiescent current of 2.5 µA. Each device contains a voltage reference unit, an error amplifier, a PMOS power transistor, resistors for setting output voltage, current limit, and temperature limit protection circuits. The NCP562 series provides an enable pin for ON/OFF control.

The NCP562/NCP563 has been designed to be used with low cost ceramic capacitors and requires a minimum output capacitor of 0.1 µF. The device is housed in the micro-miniature SC82-AB surface mount package. Standard voltage versions are 1.5, 1.8, 2.1, 2.5, 2.7, 2.8, 3.0, 3.3, 3.5 and 5.0 V. Other voltages are available in 100 mV steps.

#### Features

- Low Quiescent Current of 2.5 µA Typical
- Low Output Voltage Option
- Output Voltage Accuracy of 2.0%
- Temperature Range of -40°C to 85°C
- NCP562 Provides an Enable Pin
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

## Typical Applications

- Battery Powered Instruments
- Hand–Held Instruments
- Camcorders and Cameras



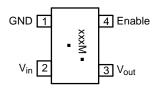
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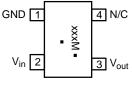


SC82-AB (SC70-4) SQ SUFFIX CASE 419C

#### **PIN CONNECTIONS &** MARKING DIAGRAMS



(NCP562 Top View)



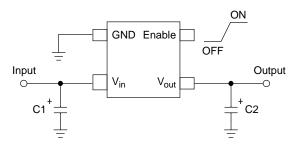
(NCP563 Top View)

- ххх = Specific Device Code Μ
  - = Month Code\*
  - = Pb-Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or position and underbar may vary depending upon manufacturing location.

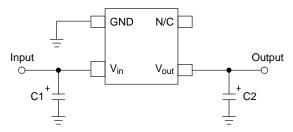
## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.



This device contains 28 active transistors

#### Figure 1. NCP562 Typical Application Diagram



This device contains 28 active transistors

Figure 2. NCP563 Typical Application Diagram

#### **PIN FUNCTION DESCRIPTION**

NCP562	NCP563	Pin Name	Description		
1	1	GND	Power supply ground.		
2	2	Vin	Positive power supply input voltage.		
3	3	Vout	Regulated output voltage.		
4	-	Enable	This input is used to place the device into low-power standby. When this input is pulled low, the device is disabled. If this function is not used, Enable should be connected to Vin.		
-	4	N/C	No internal connection.		

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage	V <sub>in</sub>	6.0	V
Enable Voltage (NCP562 ONLY)	Enable	–0.3 to V <sub>in</sub> +0.3	V
Output Voltage	V <sub>out</sub>	–0.3 to V <sub>in</sub> +0.3	V
Power Dissipation and Thermal Characteristics Power Dissipation Thermal Resistance, Junction-to-Ambient	$P_D \\ R_{\theta J A}$	Internally Limited 400	W ∘C/W
Operating Junction Temperature	TJ	+150	°C
Operating Ambient Temperature	T <sub>A</sub>	-40 to +85	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

 This device series contains ESD protection and exceeds the following tests: Human Body Model 2000 V per MIL–STD–883, Method 3015

Machine Model Method 200 V

2. Latch up capability (85°C)  $\pm\,100$  mA DC with trigger voltage.

## ELECTRICAL CHARACTERISTICS

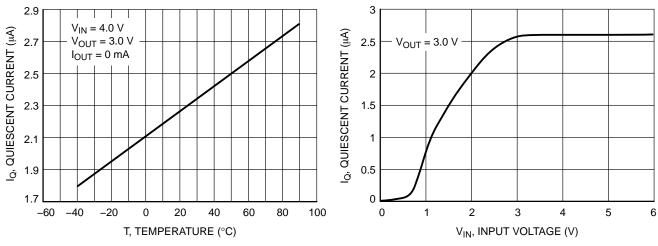
 $(V_{in} = V_{out(nom.)} + 1.0 \text{ V}, V_{enable} = V_{in}, C_{in} = 1.0 \text{ }\mu\text{F}, C_{out} = 1.0 \text{ }\mu\text{F}, T_J = 25^{\circ}\text{C}, \text{ unless otherwise noted.})$ 

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage ( $T_A = 25^{\circ}C$ , $I_{out} = 1.0 \text{ mA}$ )	V <sub>out</sub>				V
1.5 V		1.455	1.5	1.545	
1.8 V		1.746	1.8	1.854	
2.1 V		2.037	2.1	2.163	
2.5 V		2.425	2.5	2.575	
2.7 V		2.646	2.7	2.754	
2.8 V		2.744	2.8	2.856	
3.0 V		2.940	3.0	3.060	
3.3 V		3.234	3.3	3.366	
3.5 V		3.43	3.5	3.57	
5.0 V		4.9	5.0	5.1	
Line Regulation	Reg <sub>line</sub>				mV
1.5 V–4.4 V (V <sub>in</sub> = V <sub>o(nom.)</sub> + 1.0 V to 6.0 V		-	10	20	
4.5 V–5.0 V (V <sub>in</sub> = 5.5 V to 6.0 V)		-	10	20	
Load Regulation (I <sub>out</sub> = 10 mA to 80 mA)	Reg <sub>load</sub>	-	20	40	mV
Output Current (V <sub>out</sub> = (V <sub>out</sub> at I <sub>out</sub> = 80 mA) -3.0%)	I <sub>o(nom.)</sub>				mA
1.5 V to 3.9 V (V <sub>in</sub> = V <sub>out(nom.)</sub> + 2.0 V)	· · ·	80	280	_	
4.0 V–5.0 V (V <sub>in</sub> = 6.0 V)		80	280	-	
Dropout Voltage (T <sub>A</sub> = $-40^{\circ}$ C to $85^{\circ}$ C, I <sub>out</sub> = 80 mA, Measured at V <sub>out</sub> $-3.0\%$ )	V <sub>in</sub> -V <sub>out</sub>				mV
1.5 V–1.7 V		_	550	800	
1.8 V–2.4 V		_	400	550	
2.5 V-2.6 V		_	250	400	
2.7 V–2.9 V		_	230	400	
3.0 V-3.2 V		_	200	350	
3.3 V-4.9 V		_	190	350	
5.0 V		-	140	250	
Quiescent Current	Ι <sub>Q</sub>				μΑ
(Enable Input = 0 V)	3	-	0.1	1.0	•
(Enable Input = $V_{in}$ , $I_{out}$ = 1.0 mA to $I_{o(nom.)}$ )		-	2.5	6.0	
Output Short Circuit Current	I <sub>out(max)</sub>				mA
$1.5 \text{ V to } 3.9 \text{ V} (\text{V}_{\text{in}} = \text{V}_{\text{nom}} + 2.0 \text{ V})$	Car(max)	150	300	600	
4.0 V–5.0 V (V <sub>in</sub> = 6.0 V)		150	300	600	
Output Voltage Noise (f = 100 Hz to 100 kHz, $V_{out}$ = 3.0 V)	V <sub>n</sub>	-	100	-	μVrms
Enable Input Threshold Voltage (NCP562 ONLY)	V <sub>th(en)</sub>				V
(Voltage Increasing, Output Turns On, Logic High)		1.3	-	-	
(Voltage Decreasing, Output Turns Off, Logic Low)		_	-	0.3	
Output Voltage Temperature Coefficient	Т <sub>С</sub>	_	±100		ppm/°C

3. Maximum package power dissipation limits must be observed.

$$PD = \frac{T_{J(max)} - T_{A}}{R_{\theta JA}}$$

4. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.







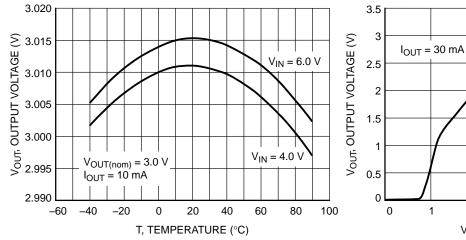


Figure 5. Output Voltage versus Temperature



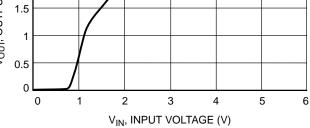
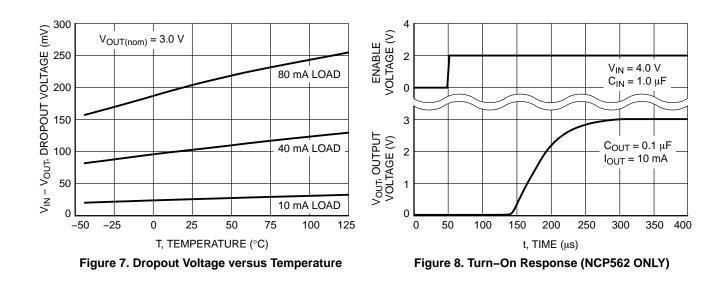
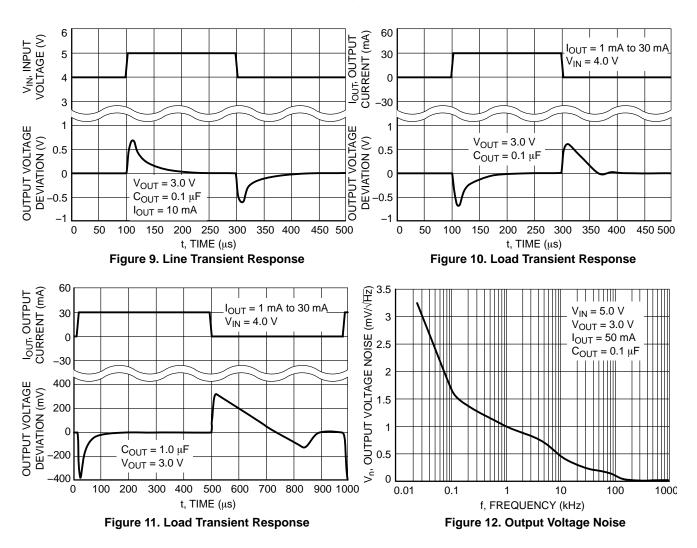


Figure 6. Output Voltage versus Input Voltage





#### DEFINITIONS

#### Load Regulation

The change in output voltage for a change in output current at a constant temperature.

#### **Dropout Voltage**

The input/output differential at which the regulator output no longer maintains regulation against further reductions in input voltage. Measured when the output drops 3.0% below its nominal. The junction temperature, load current, and minimum input supply requirements affect the dropout level.

#### **Maximum Power Dissipation**

The maximum total dissipation for which the regulator will operate within its specifications.

#### **Quiescent Current**

The quiescent current is the current which flows through the ground when the LDO operates without a load on its output: internal IC operation, bias, etc. When the LDO becomes loaded, this term is called the Ground current. It is actually the difference between the input current (measured through the LDO input pin) and the output current.

#### Line Regulation

The change in output voltage for a change in input voltage. The measurement is made under conditions of low dissipation or by using pulse technique such that the average chip temperature is not significantly affected.

#### Line Transient Response

Typical over and undershoot response when input voltage is excited with a given slope.

#### **Thermal Protection**

Internal thermal shutdown circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated at typically 160°C, the regulator turns off. This feature is provided to prevent failures from accidental overheating.

#### Maximum Package Power Dissipation

The maximum power package dissipation is the power dissipation level at which the junction temperature reaches its maximum operating value, i.e. 125°C. Depending on the ambient power dissipation and thus the maximum available output current.

## **APPLICATIONS INFORMATION**

A typical application circuit for the NCP562 and NCP563 series are shown in Figure 1 and Figure 2.

### Input Decoupling (C1)

A 1.0  $\mu$ F capacitor either ceramic or tantalum is recommended and should be connected close to the NCP562 package. Higher values and lower ESR will improve the overall line transient response.

TDK capacitor: C2012X5R1C105K, or C1608X5R1A105K

## **Output Decoupling (C2)**

The NCP562 and NCP563 are very stable regulators and do not require any specific Equivalent Series Resistance (ESR) or a minimum output current. Capacitors exhibiting ESRs ranging from a few m $\Omega$  up to 10  $\Omega$  can thus safely be used. The minimum decoupling value is 0.1 µF and can be augmented to fulfill stringent load transient requirements. The regulator accepts ceramic chip capacitors as well as tantalum devices. Larger values improve noise rejection and load regulation transient response.

TDK capacitor: C2012X5R1C105K, C1608X5R1A105K, or C3216X7R1C105K

## Enable Operation (NCP562 ONLY)

The enable pin will turn on the regulator when pulled high and turn off the regulator when pulled low. These limits of threshold are covered in the electrical specification section of this data sheet. If the enable is not used, then the pin should be connected to  $V_{\rm in}$ .

## Hints

Please be sure the Vin and GND lines are sufficiently wide. When the impedance of these lines is high, there is a chance to pick up noise or cause the regulator to malfunction. Place external components, especially the output capacitor, as close as possible to the circuit, and make leads as short as possible.

## Thermal

As power across the NCP562 and NCP563 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material and also the ambient temperature effect the rate of temperature rise for the part. This is stating that when the devices have good thermal conductivity through the PCB, the junction temperature will be relatively low with high power dissipation applications.

The maximum dissipation the package can handle is given by:

$$PD = \frac{T_{J(max)} - T_{A}}{R_{\theta JA}}$$

If junction temperature is not allowed above the maximum  $125^{\circ}$ C, then the NCP562 and NCP563 can dissipate up to  $250 \text{ mW} @ 25^{\circ}$ C.

The power dissipated by the NCP562 and NCP563 can be calculated from the following equation:

$$P_{tot} = [V_{in} * I_{gnd} (I_{out})] + [V_{in} - V_{out}] * I_{out}$$

or

$$V_{inMAX} = \frac{P_{tot} + V_{out} * I_{out}}{I_{gnd} + I_{out}}$$

If an 80 mA output current is needed then the ground current from the data sheet is 2.5  $\mu$ A. For an NCP562 or NCP563 (3.0 V), the maximum input voltage will then be 6.0 V.

#### **ORDERING INFORMATION**

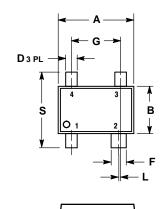
Device	Nominal Output Voltage	Marking	Package	Shipping†	
NCP562SQ15T1G	1.5	LDI			
NCP562SQ18T1G	1.8	LEY			
NCP562SQ21T1G	2.1	AAA			
NCP562SQ25T1G	2.5	LDK			
NCV562SQ25T1G*	2.5	AAG			
NCP562SQ27T1G	2.7	LEZ			
NCP562SQ28T1G	2.8	LDL			
NCP562SQ30T1G	3.0	LDM		3000 / Tape & Reel	
NCP562SQ33T1G		LDN			
NCV562SQ33T1G*	3.3	AAE			
NCP562SQ35T1G	3.5	LJU			
NCP562SQ50T1G	5.0	LDP	SC82-AB		
NCP563SQ15T1G	4.5	1.00	3002-AB		
NCV563SQ15T1G*	1.5	LDQ			
NCP563SQ18T1G	1.0	LFA			
NCV563SQ18T1G*	1.8	LFA			
NCP563SQ25T1G	2.5	LDS			
NCP563SQ27T1G	2.7	LFB			
NCP563SQ28T1G	2.8	LDT			
NCP563SQ30T1G	2.0				
NCV563SQ30T1G*	3.0	LDU			
NCP563SQ33T1G	3.3				
NCV563SQ33T1G*	3.3	LDV			
NCP563SQ50T1G	5.0	LDX			

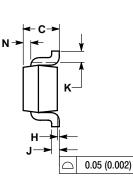
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable

#### PACKAGE DIMENSIONS

SC-82AB CASE 419C-02 **ISSUE F** 





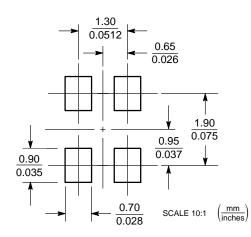
NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.

2 419C-01 OBSOLETE. NEW STANDARD IS 3.

419C-02. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE 4 BURRS.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.80	2.20	0.071	0.087	
В	1.15	1.35	0.045	0.053	
С	0.80	1.10	0.031	0.043	
D	0.20	0.40	0.008	0.016	
F	0.30	0.50	0.012	0.020	
G	1.10	1.50	0.043	0.059	
н	0.00	0.10	0.000	0.004	
J	0.10	0.26	0.004	0.010	
K	0.10		0.004		
L	0.05 BSC		0.002 BSC		
N	0.20 REF		0.008 REF		
S	1.80	2.40	0.07	0.09	

**SOLDERING FOOTPRINT\*** 



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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NCP562SQ33T1G	NCP562SQ50T1G	NCP563SQ15T1G	NCP563SQ18T1G	NCP563SQ25T1G	NCP563SQ27T1G
NCP563SQ28T1G	NCP563SQ30T1G	NCP563SQ33T1G	NCP563SQ50T1G	NCV562SQ33T1G	NCP562SQ35T1G
NCP562SQ21T1G	NCV563SQ15T1G				